TOSHIBA

TOSHIBA Diode Silicon Epitaxial Planar Type

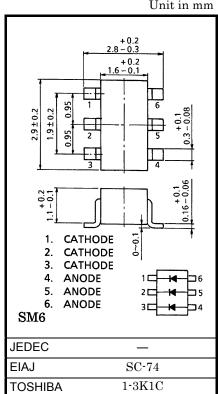
# HN2D01F

Ultra High Speed Switching Application

- HN2D01F is composed of 3 independent diodes.
- Low forward voltage  $: V_{F(3)} = 0.98V (typ.)$
- Fast reverse recovery time:  $t_{rr} = 1.6ns$  (typ.)
- Small total capacitance  $C_{\rm T} = 0.5 \mu F (typ.)$

### Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit	
Maximum (peak) reverse Voltage	V <sub>RM</sub>	85	V	
Reverse voltage	V <sub>R</sub>	80	V	
Maximum (peak) forward current	I <sub>FM</sub>	240 (*)	mA	
Average forward current	Ι <sub>Ο</sub>	80 (*)	mA	
Surge current (10ms)	I <sub>FSM</sub>	1 (*)	А	
Power dissipation	Р	300	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	T <sub>stg</sub>	-55~125	°C	



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

temperature, etc.) may cause this product to decrease in the

reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(\*) This is absolute maximum rating of single diode (Q1 or Q2 or Q3). In the case of using 2 ro 3 diodes, the absolute maximum ratings per diodes is 75 %f the single diode one.

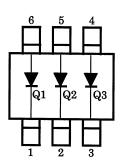
### Electrical Characteristics (Q1, Q2, Q3 Common Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Forward voltage	V <sub>F (1)</sub>	_	I <sub>F</sub> = 1mA		0.62		V
	V <sub>F (2)</sub>	—	I <sub>F</sub> = 10mA		0.75		
	V <sub>F (3)</sub>	_	I <sub>F</sub> = 100mA	-	0.98	1.20	
Reverse current	I <sub>R (1)</sub>	_	V <sub>R</sub> = 30V	-	_	0.1	μA
	I <sub>R (2)</sub>	_	V <sub>R</sub> = 80V			0.5	
Total capacitance	CT	_	V <sub>R</sub> = 0, f = 1MH <sub>z</sub>		0.5	3.0	pF
Reverse recovery time	t <sub>rr</sub>	_	I <sub>F</sub> = 10mA (Fig.1)		1.6	4.0	ns

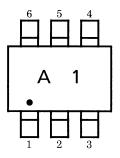
Weight: 0.015g

Unit in mm

Pin Assignment (Top View)

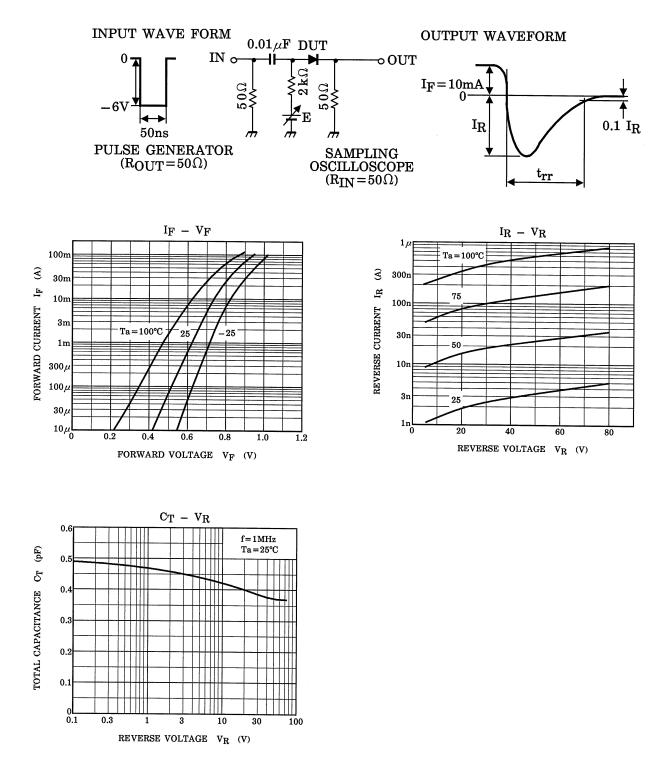


Marking



## **TOSHIBA**

### Fig.1 Reverse Recovery Time (trr) Test Circuit



#### **RESTRICTIONS ON PRODUCT USE**

20070701-EN GENERAL

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